## NSN 5961-01-089-2200



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-089-2200 **Inclosure Material:** Metal **Overall Length:** 0.260 inches **Terminal Length:** 1.500 inches **Overall Diameter:** 0.335 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-5 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 45.0 breakdown voltage, collector-to-base, emitter open and 3.5 breakdown voltage, emitter-to-base, collector open and 45.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 3.50 amperes source cutoff current and 1.00 amperes source cutoff current **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** 

Fiig: A110a0

No

**Demilitarization:**